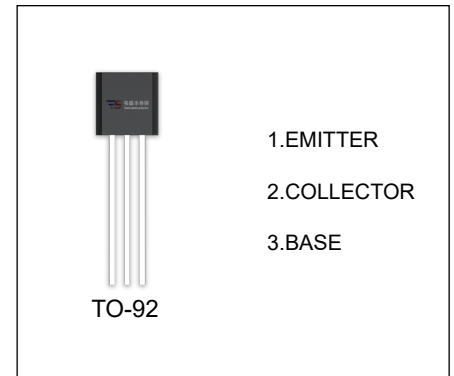


## MPSA93 TRANSISTOR (PNP)

### FEATURES

- General Purpose Amplifier



### ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
MPSA93	TO-92	Bulk	1000pcs/Bag
MPSA93-TA	TO-92	Tape	2000pcs/Box

### MAXIMUM RATINGS ( $T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	-200	V
$V_{CEO}$	Collector-Emitter Voltage	-200	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current	-0.5	A
$P_C$	Collector Power Dissipation	625	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	200	$^{\circ}\text{C}/\text{W}$
$T_J, T_{stg}$	Operation Junction and Storage Temperature Range	-55~+150	$^{\circ}\text{C}$

$T_a=25\text{ }^\circ\text{C}$  unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-0.1\text{mA}, I_E=0$	-200			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}^*$	$I_C=-1\text{mA}, I_B=0$	-200			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-0.1\text{mA}, I_C=0$	-5			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=-160\text{V}, I_E=0$			-0.25	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=-3\text{V}, I_C=0$			-0.1	mA
DC current gain	$h_{FE(1)}^*$	$V_{CE}=-10\text{V}, I_C=-1\text{mA}$	25			
	$h_{FE(2)}^*$	$V_{CE}=-10\text{V}, I_C=-10\text{mA}$	40			
	$h_{FE(3)}^*$	$V_{CE}=-10\text{V}, I_C=-30\text{mA}$	25			
Collector-emitter saturation voltage	$V_{CE(sat)}^*$	$I_C=-20\text{mA}, I_B=-2\text{mA}$			-0.4	V
Base-emitter saturation voltage	$V_{BE(sat)}^*$	$I_C=-20\text{mA}, I_B=-2\text{mA}$			-0.9	V
Transition frequency	$f_T$	$V_{CE}=-20\text{V}, I_C=-10\text{mA}, f=100\text{MHz}$	50			MHz

\*Pulse test: pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2.0\%$ .

# Typical Characteristics

# MPSA93

